

Silicon Bridge Rectifier

$V_{RRM} = 50 \text{ V} - 1000 \text{ V}$

$I_F = 2 \text{ A}$

Features

- Types up to 1000 V V_{RRM}
- Ideal for printed circuit board
- Built-in printed circuit board stand-offs
- High temperature soldering guaranteed 265°C/ 10 seconds
- High case dielectric strength
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0

KBP Package

Mechanical Data

Case: Reliable low cost construction

Weight: 0.065 oz, 2.2 g

Mounting position: Any

Terminals: Plated leads, solderable per MIL-STD-202, Method 208



Maximum ratings, at $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	KBP201	KBP202	KBP203	KBP204	Unit
Repetitive peak reverse voltage	V_{RRM}		50	100	200	400	V
RMS reverse voltage	V_{RMS}		35	70	140	280	V
DC blocking voltage	V_{DC}		50	100	200	400	V
Continuous forward current	I_F	$T_C \leq 50^\circ\text{C}$	2	2	2	2	A
Surge non-repetitive forward current, Half Sine Wave	$I_{F,SM}$	$T_C = 25^\circ\text{C}$, $t_p = 8.3 \text{ ms}$	60	60	60	60	A
Operating temperature	T_j		-50 to 150	-50 to 150	-50 to 150	-50 to 150	$^\circ\text{C}$
Storage temperature	T_{stg}		-50 to 150	-50 to 150	-50 to 150	-50 to 150	$^\circ\text{C}$

Electrical characteristics, at $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Conditions	KBP201	KBP202	KBP203	KBP204	Unit
Diode forward voltage	V_F	$I_F = 2 \text{ A}$, $T_j = 25^\circ\text{C}$	1.1	1.1	1.1	1.1	V
Reverse current	I_R	$V_R = 50 \text{ V}$, $T_j = 25^\circ\text{C}$	10	10	10	10	μA
		$V_R = 50 \text{ V}$, $T_j = 100^\circ\text{C}$	200	200	200	200	

Thermal characteristics

Thermal resistance, junction - case	R_{thJL}		25.0	25.0	25.0	25.0	$^\circ\text{C/W}$
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